

## UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria. Virginia 22313-1450

Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/666,220	09/19/2003	Hyun-Jin Cho	C002-D-2	8470	
7.	590 04/01/2005		EXAM	INER	
H.C. Chan			TRAN, MAI HUONG C		
T-RAM, Inc.					
100 Headquarters Drive			ART UNIT	PAPER NUMBER	
San Jose, CA 95134-1370			2818		

DATE MAILED: 04/01/2005

Please find below and/or attached an Office communication concerning this application or proceeding.



## UNITED STATES DEPARTMENT OF COMMERCE

U.S. Patent and Trademark Office Address: COMMISSIONER FOR PATENTS

P.O. Box 1450

Alexandria, Virginia 22313-1450

AR

APPLICATION NO./	FILING DATE	FIRST NAMED INVENTOR /	ATTORNEY DOCKET NO.	
CONTROL NO.		PATENT IN REEXAMINATION	<u></u>	
			EXAMINER	

ART UNIT PAPER

032405

DATE MAILED:

Please find below and/or attached an Office communication concerning this application or proceeding.

## **Commissioner for Patents**

PTO 1449 dated 3/18/04 has been received and partially considered except three non patent literature documents. In order for these documents to be considered, please submit a copy of these documents.

- Namati, Farid and Plummer, James, D., A novel High Density, Low Voltage SRAM Cell with a Vertical NDR Device.
- Namati, Farid and Plummer, James, D., A Novel Thyristor-based SRAM Cell for high-speed, low-voltage, giga-scale memories.

- Gribnikov, Z.S., Korobov, V.Al, and Mitin, v.v., The Tunnel Diode as a Thyristor Emitter, Solid-State Electronics.

Davidelius Superiista zaren kansiner

Teonirwing, Center 2800